TIG056BF

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N-Channel IGBT 430V, 240A, VCE(sat); 3.6V TO-220F-3FS

Features

- · Low-saturation voltage
- · Ultrahigh speed switching
- · Enhansment type

· Protection diode in

Specifications

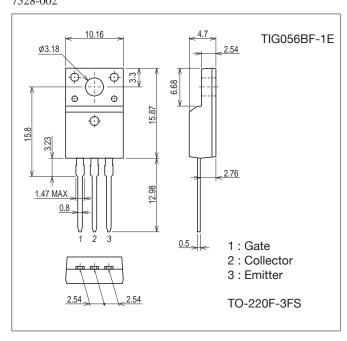
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector to Emitter Voltage	VCES		430	V
Gate to Emitter Voltage	VGES		±33	V
Collector Current (Pulse)	ICP	V _{GE} =15V, C _M =2000μF	240	Α
Allowable Power Dissipation	PD	Tc=25°C	30	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit: mm (typ) 7528-002



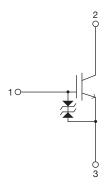
Ordering & Package Information

Device	Package	Shipping	memo	
TIG056BF-1E	TO-220F-3FS SC-67	50 pcs./magazine	Pb-Free	

Marking

Electrical Connection

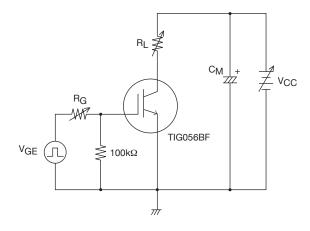


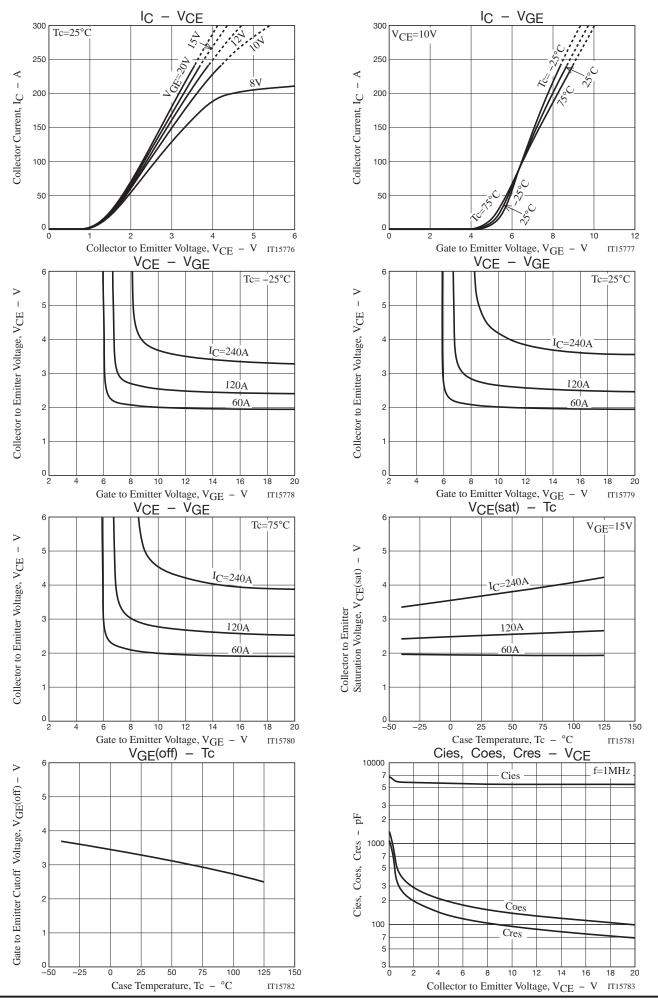


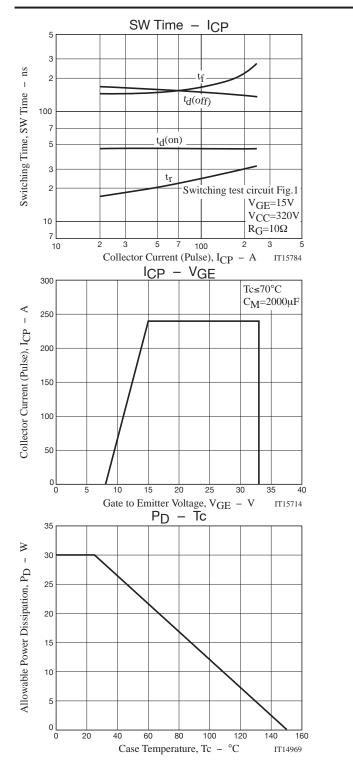
Electrical Characteristics at Ta=25°C

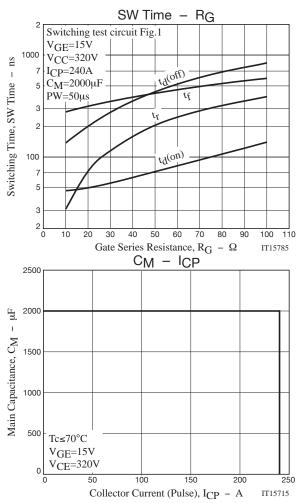
Parameter	Symbol	Conditions	Ratings			Unit
Parameter			min	typ	max	Oill
Collector to Emitter Breakdown Voltage	V(BR)CES	IC=2mA, VGE=0V	430			V
Collector to Emitter Cutoff Current	ICES	V _{CE} =320V, V _{GE} =0V			100	μΑ
Gate to Emitter Leakage Current	IGES	V _{GE} =±30V, V _{CE} =0V			±10	μΑ
Gate to Emitter Threshold Voltage	V _{GE} (off)	V _{CE} =10V, I _C =1mA	2.5		5.0	V
Collector to Emitter Saturation Voltage	VCE(sat)	IC=240A, VGE=15V		3.6	5.0	V
Input Capacitance	Cies	V _{CE} =20V, f=1MHz		5500		рF
Output Capacitance	Coes			100		pF
Reverse Transfer Capacitance	Cres			70		рF
Turn-ON Delay Time	t _d (on)	V _{CE} =320V, I _C =240A, V _{GE} =15V, R _G =10Ω		46		ns
Rise Time	tr			32		ns
Turn-OFF Delay Time	t _d (off)			140		ns
Fall Time	t _f			270		ns

Fig1 Large Current R Load Switching Circuit



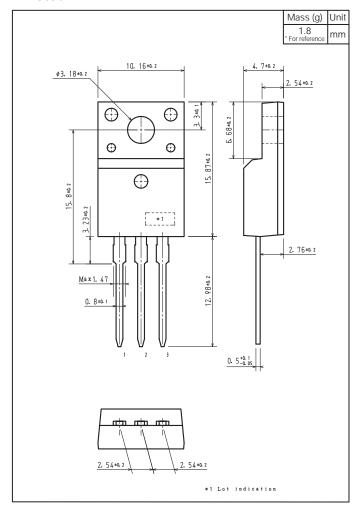






Outline Drawing

TIG056BF-1E



Note on usage: TIG056BF has protection diode between gate and emitter but handling it requires sufficient care to be taken.

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